

Novel two-dimensional Janus TiSiGeN₄ monolayer with N vacancies for efficient photocatalytic nitrogen reduction

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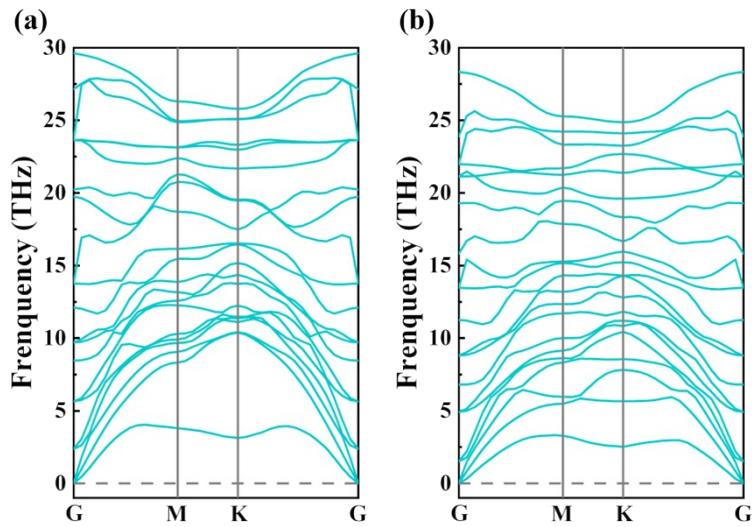


Fig. S1 Phonon dispersion curves for (a) TiSi_2N_4 and (b) TiSiGeN_4 .

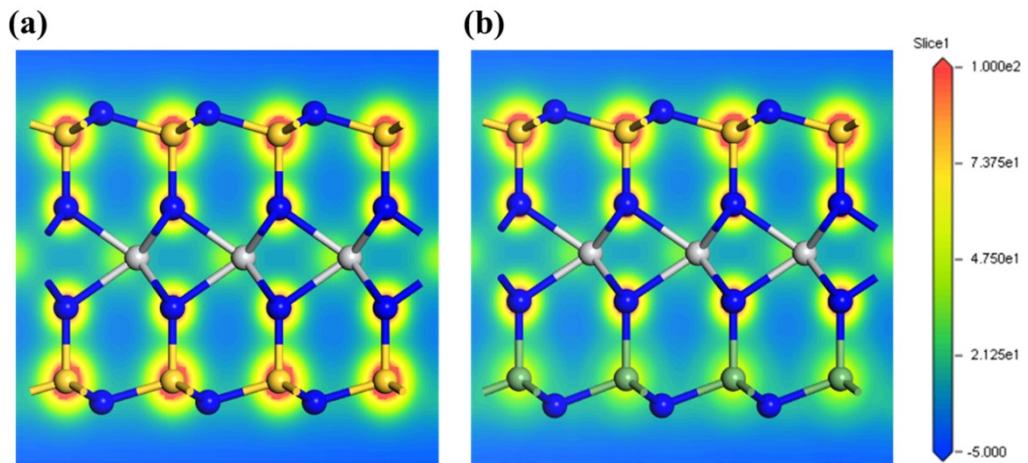


Fig. S2 Profile of electrostatic potential of (a) TiSi_2N_4 and (b) TiSiGeN_4 . The different colors in the picture represent different electron densities, as shown in the scale on the right.

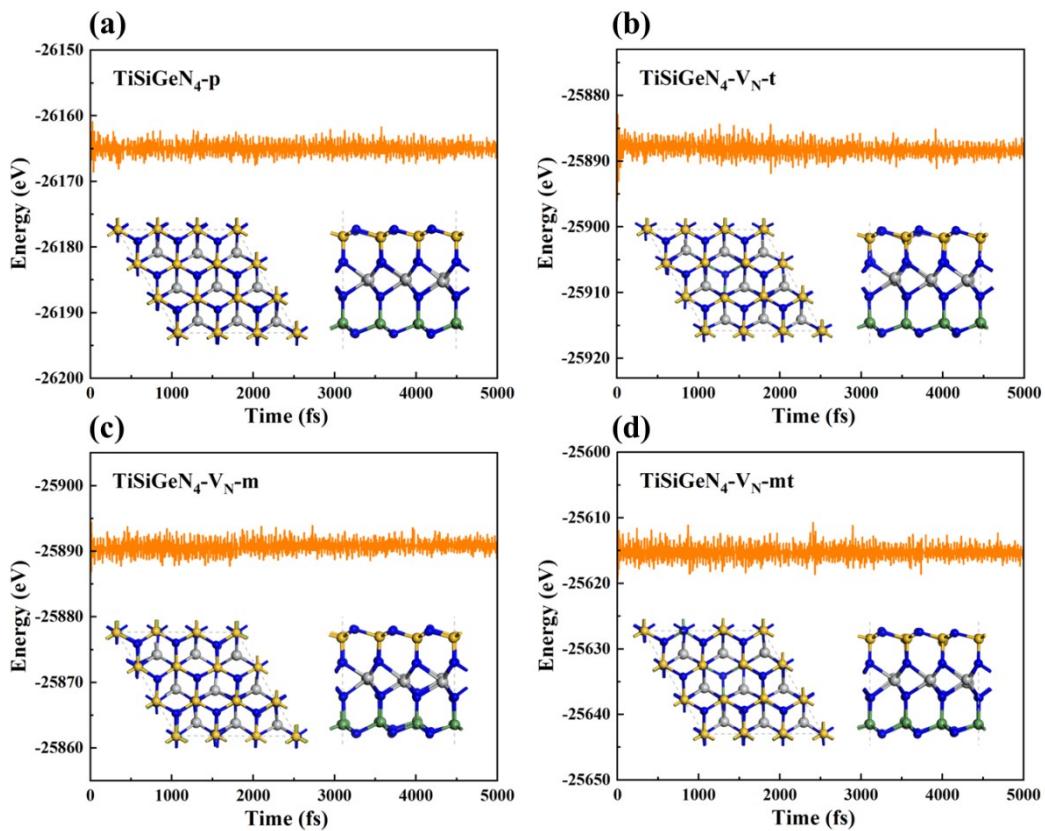


Fig. S3 Variations of the total energy versus time for AIMD simulations of Janus TiSiGeN_4 with different N vacancies. The AIMD runs under 500 K for 5 ps with a time step of 1 fs.

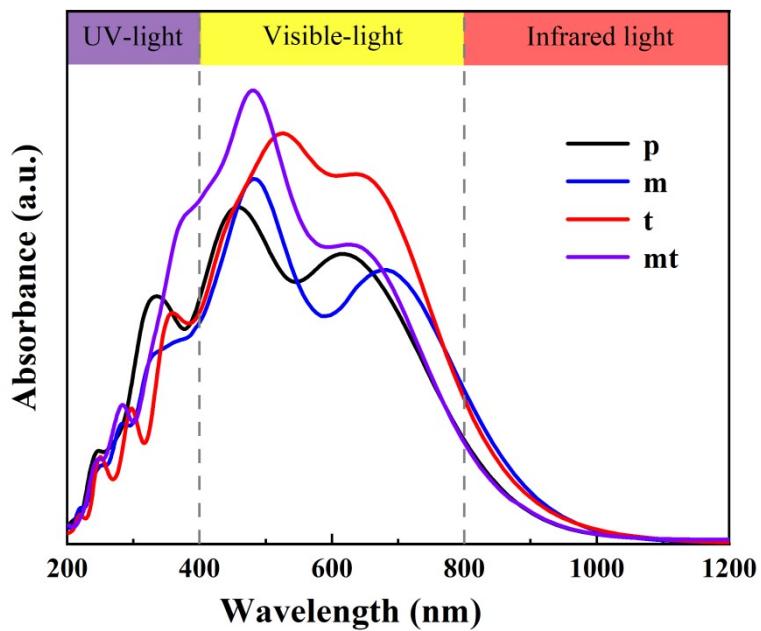


Fig. S4 Optical absorption spectra of $\text{TiSiGeN}_4\text{-p}$, $\text{TiSiGeN}_4\text{-VN-t}$, $\text{TiSiGeN}_4\text{-VN-m}$, and $\text{TiSiGeN}_4\text{-VN- mt}$.

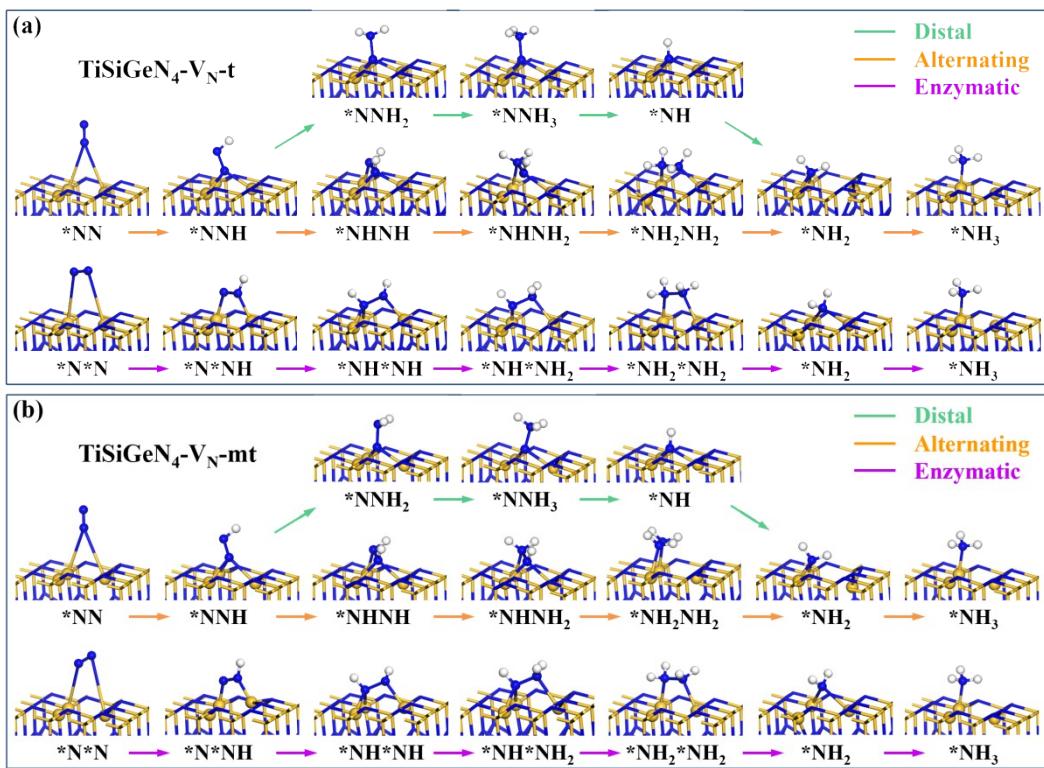


Fig. S5 Optimized structures of various intermediates along the reaction paths of the NRR

proceeding on the (a) $\text{TiSiGeN}_4\text{-VN-t}$ and (b) $\text{TiSiGeN}_4\text{-VN-mt}$ surfaces through distal, alternating and enzymatic pathways.

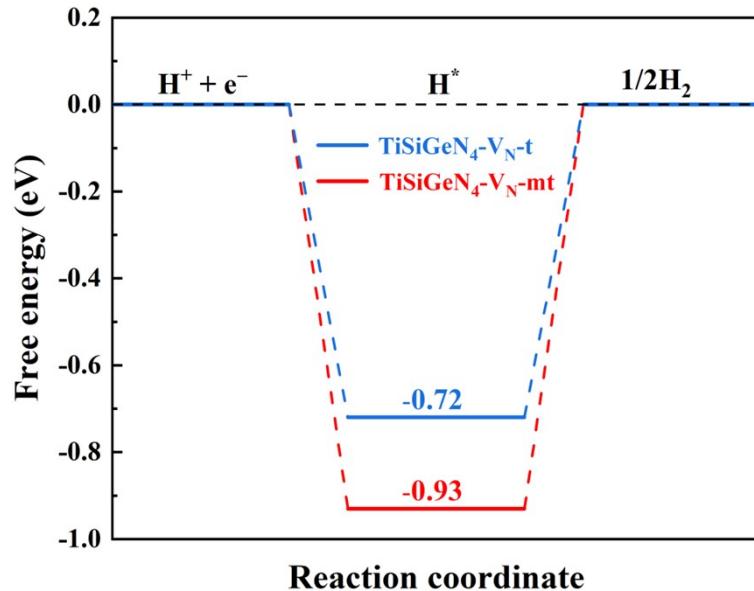


Fig. S6 Free energy diagrams for HER on $\text{TiSiGeN}_4\text{-VN-t}$ and $\text{TiSiGeN}_4\text{-VN-mt}$.

Table S1 Free energy corrections: E_{ZPE} and S represent the zero-point energy change and the entropy change of intermediate for NRR on TiSiGeN₄-V_{N-t}, where * denoted the adsorption site.

Species	E_{ZPE} (eV)	TS (eV)	$E_{ZPE} - TS$ (eV)
*NN	0.23	0.08	0.15
*NNH	0.55	0.09	0.46
*NNH ₂	0.84	0.11	0.73
*NNH ₃	1.01	0.13	0.88
*NH	0.41	0.03	0.38
*NH ₂	0.69	0.09	0.60
*NH ₃	0.96	0.12	0.84
*NHNH	0.80	0.11	0.69
*NHNH ₂	0.99	0.14	0.85
*NH ₂ NH ₂	1.27	0.16	1.11
*N*N	0.21	0.06	0.15
*N*NH	0.53	0.08	0.45
*NH*NH	0.79	0.10	0.69
*NH*NH ₂	0.91	0.16	0.75
*NH ₂ *NH ₂	1.24	0.18	1.06
*NH ₂	0.68	0.08	0.60
*NH ₃	0.96	0.12	0.84
*H	0.18	0.16	0.02
H ₂	0.27	0.41	-0.14
N ₂	0.15	0.60	-0.45

NH_3	0.94	0.60	0.34
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Table S2. Free energy corrections: E_{ZPE} and S represent the zero-point energy change and the entropy change of intermediate for NRR on $\text{TiSiGeN}_4\text{-V}_{\text{N}}\text{-mt}$, where * denoted the adsorption site.

Species	E_{ZPE} (eV)	TS (eV)	$E_{\text{ZPE}} - TS$ (eV)
*NN	0.25	0.10	0.15
*NNH	0.57	0.10	0.47
*NNH ₂	0.86	0.11	0.75
*NNH ₃	1.09	0.12	0.97
*NH	0.45	0.03	0.42
*NH ₂	0.69	0.09	0.60
*NH ₃	0.92	0.16	0.76
*NHNH	0.82	0.09	0.73
*NHNH ₂	1.00	0.14	0.86
*NH ₂ NH ₂	1.30	0.18	1.12
*N*N	0.28	0.04	0.15
*N*NH	0.56	0.04	0.45
*NH*NH	0.84	0.06	0.78
*NH*NH ₂	0.99	0.10	0.89
*NH ₂ *NH ₂	1.25	0.17	1.08
*NH ₂	0.70	0.09	0.61
*NH ₃	0.93	0.17	0.76
*H	0.18	0.17	0.01

\mathbf{H}_2	0.27	0.41	-0.14
\mathbf{N}_2	0.15	0.60	-0.45
\mathbf{NH}_3	0.94	0.60	0.34